

Description

The HZ20006000-100NA1 is a highly reliable amplifier. It employs ultra-wideband GaN transistors that can output 100 watts of power within the 2000MHz to 6000MHz frequency range while maintaining relevant RF performance. In contrast to traditional CW amplifiers, this amplifier can amplify spread-spectrum signals, with an instantaneous bandwidth of up to 200 MHz. When paired with the appropriate SDR digital excitation source, it can produce excellent jamming performance on remote control, data transmission, and positioning signals. Therefore, this amplifier is particularly suitable for use in wireless communication interference systems in the L, S and C bands, including but not limited to mobile phones, radio stations, and drones.



Application and Feature

- Utilizing third-generation GaN transistors
- Ultra-wide working bandwidth and instant bandwidth
- Excellent reliability
- Features temperature detection, standing-wave detection, and protection functions
- RS485 serial interface for monitoring and control [\[note1\]](#)

Specifications of Products

Electrical Specifications					
Parameter	Min	Typ	Max	Unit	Test Condition
Operating frequency	2000		6000	MHz	
Instant bandwidth			200	MHz	Broadband signal, such as OFDM signal
Output power (P _{sat})	80	100		W	CW signal
Gain (small signal)	41		51	dB	Measured with VNA in swept frequency mode at -20dBm. Input power calibrated/measured at the amplifier input port.
Gain flatness (small signal)	-3		3	dB	Test condition the same as Gain
Gain adjustment range [note1]	20			dB	Test condition the same as Gain
Input RF power range	-7		6	dBm	
Gain adjustment step size [note1]	0.5			dB	Test condition the same as Gain
Noise figure			20	dB	
Input VSWR			1.8		Measured with VNA in swept frequency mode at -20dBm. Input power calibrated/measured at the amplifier input port.
Spurious		-60		dBc	CW signal at the output power of 100W. Spurious defined as any non-harmonic amplifier output. Spurious measured in a 1kHz resolution bandwidth, 10kHz video bandwidth. Specifications apply at offsets of greater than or equal to ± 10 kHz from the RF carrier. Maximum measurement frequency is 8GHz
Harmonics(2 nd , 3 rd)	-10			dBc	CW signal source at output power of 100W
Operating voltage	24	28	32	V	Note: Output power capabilities and gain will vary with voltage
Operating current		19	24	A	CW signal source at output power of 100W
PA Enable/Disable time			1	μ s	Measurement with of 100W CW



HZ20006000-100NA1

100W-Solid State Broadband High Power Amplifier

Electrical Specifications

Parameter	Min	Typ	Max	Unit	Test Condition
					output.Rise and fall time of amplifier output envelope recorded.Rise and fall times at 10%-90% of the output power in linear scale.PA Enable/Disable signal set to 10kHz repetition rate and 50% duty cycle

Alarm and Protection

Parameter	Introductions
Over temperature	When the temperature exceeds $80^{\circ}\text{C}\pm 5^{\circ}\text{C}$, the amplifier PIN7 will outputs +3.3V voltage and the amplifier will automatically shut down; When the temperature drops below $70^{\circ}\text{C}\pm 5^{\circ}\text{C}$, the amplifier will automatically turn on.
Over VSWR	When the output port of the amplifier is open or short,the amplifier PIN7 will outputs +3.3V voltage and the amplifier shut down,the status will be locked . The alarm state will be cleared once pin 15 transmits a pulse signal
Over voltage [note1]	The amplifier PIN7 will outputs +3.3V voltage and the amplifier shut down when the voltage exceeds 32V,the status will be locked. The alarm state will be cleared once pin 15 transmits a pulse signal
Over current [note1]	The amplifier PIN7 will outputs +3.3V voltage and the amplifier shut down when the current exceeds 26A.,the status will be locked. The alarm state will be cleared once pin 15 transmits a pulse signal

Environmental Specifications

Parameter	Min	Typ	Max	Unit
Operating temperature	-40		+60	°C
Storage temperature	-55		+85	°C
Relative Humidity (non-condensing)			+95	%
Altitude	MIL-STD-810F Method 500.4			
Vibration/Shock	Pass MIL-STD-810F - Method 514.5/516.5 – Proc I			

Mechanical Specifications

Parameter	Value	Unit
Dimension	200 x 158x 25	mm
Weight	1.4	kg
RF Connectors In/Out	Input: SMA-F Output: N-F	-
Control Connector	D-Sub 15-Pin Female	-
Power Supply Connector	Pull-core Capacitance	-
Cooling	External Heat sink	-

DC Interface Connector

PIN#	Description	Specification
Grounding Post	GND	Ground Return
Pull-core Capacitance	VDD	Supply Voltage:+24V~32V,+28V Nominal
1	RS485 (-) [note1] [note2]	Serial Communication Bus
2	Temperature Reporting	Analog Output Voltage @ 10mV/°C with a 500mV offset (i.e. 0.75V = 25°C)
3	Address 1 (Reserved)	Hardware Address 1
4	Address 3 (Reserved)	Hardware Address 3
5	Attenuator setting [note1]	Voltage input in the range of 0.5-3.0VDC, 0.5VDC corresponds with minimum attenuation, 3.0VDC is maximum attenuation.

DC Interface Connector		
PIN#	Description	Specification
6	PA Enable	0/3.3V logic levels: Power Amplifier disable is a TTL Logic Low (0V). (Internally Pulled-High 3.3V)
7	Alarm	Amplifier Alarm indicator: Normally TTL Low A logic High indicates a fault condition, 0/3.3V Logic Levels
8	RS485(+)(Reserved) [note1] [note2]	Serial Communication Bus
9	Current Reporting	Analog output voltage range of 0.1V/1A (i.e. 1.9V = 19A)
10	Address 0(Reserved)	Hardware Address 0 – Least significant bit
11	Address 2 (Reserved)	Hardware Address 2
12	Address 4 (Reserved)	Hardware Address 4 – Most significant bit
13	Not Used	No Connection
14	Not Used	No Connection
15	Reset	Hardware reset Logic 0V to reset PA and clear latched faults

[\[note1\]](#) : This function is optional, and the optional model number is HZ20006000-100NA2.

[\[note2\]](#) : This function is optional, and the optional model number is HZ20006000-100NA2.
The RS485 master-slave communication function can be used to monitor the operational parameters of the power amplifier module, such as voltage, current, output power, and standing wave, and it can also be used to set the control parameters of the power amplifier in real time, such as power amplifier on/off, gain adjustment, power adjustment, and alarm reset.

Outline Drawing

HZ20006000-100NA1

100W-Solid State Broadband High Power Amplifier

